



A Product Line of **Diodes Incorporated**



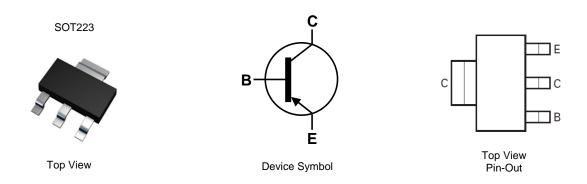
30V PNP MEDIUM POWER TRANSISTOR IN SOT223

Features

- $BV_{CEO} > -30V$
- I_C = -5.5A High Continuous Collector Current
- I_C = -20A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < -140mV @ -1A
- hFE Specified up to -20A for a High Gain Hold-Up
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- **PPAP Capable (Note 4)**

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.112 grams (Approximate)



Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FZT949TA	AEC-Q101	FZT949	7	12	1,000
FZT949QTA	Automotive	FZT949	7	12	1,000
Notes: 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.					

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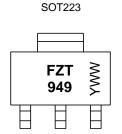
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



FZT 949 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 5= 2015) WW or $\overline{W}W =$ Week Code (01~53)





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-50	V
Collector-Emitter Voltage	V _{CEO}	-30	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-5.5	А
Peak Pulse Current	I _{CM}	-20	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 6)	6	3.0 24	W	
Linear Derating Factor	(Note 7)	P _D	1.6 12.8	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 6)	R _{θJA}	42		
merman Resistance, Junction to Ambient	(Note 7)	$R_{ hetaJA}$	78	°C/W	
Thermal Resistance Junction to Lead	(Note 8)	$R_{ extsf{ heta}JL}$	8.8		
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C	

ESD Ratings (Note 9)

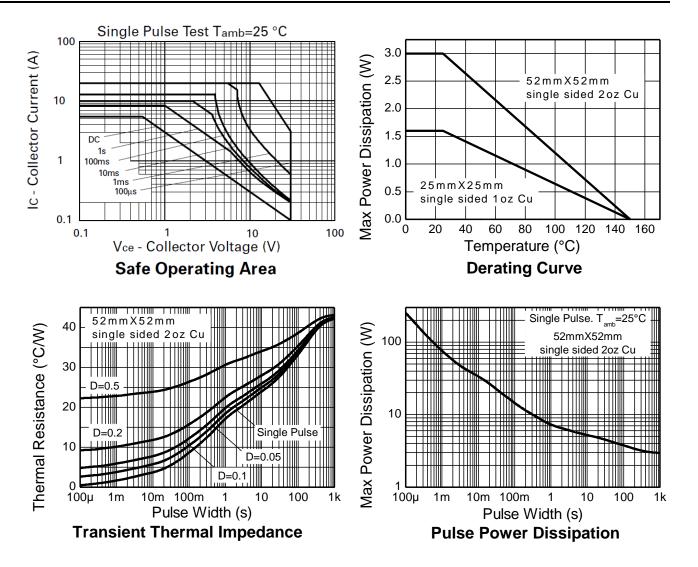
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

6. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
7. Same as Note 6, except mounted on 25mm x 25mm 1oz copper.
8. Thermal resistance from junction to solder-point (at the end of the collector lead).
9. Refer to JEDEC specification JESD22-A114 and JESD22-A115. Notes:





Thermal Characteristics and Derating Information







Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

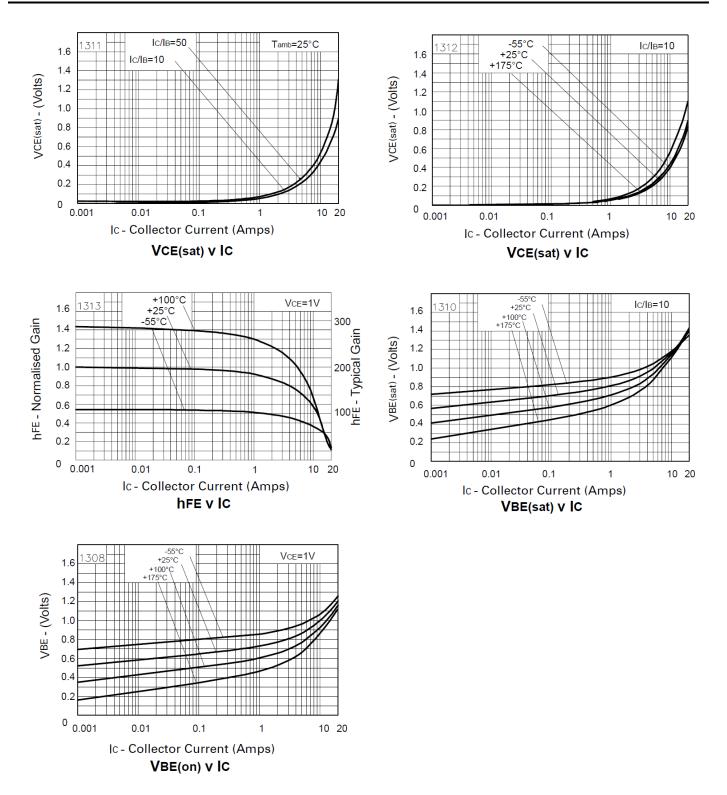
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Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-50	-80	-	V	I _C = -100μΑ
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CER}	-50	-80	-	V	$I_C = -1\mu A, R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Note 10)	BV _{CEO}	-30	-45	-	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	-8	-	V	I _E = -100μA
Collector Cut-Off Current	lana	-	-	-50	nA	V _{CB} = -40V
	I _{СВО}	-	-	-1	μA	$V_{CB} = -40V, T_A = +100^{\circ}C$
Collector Cut-Off Current	ICER	-	-	-50	nA	$V_{CB} = -40V$
	R ≤1kΩ	-	-	-1	μA	$V_{CB} = -40V, T_A = +100^{\circ}C$
Emitter Cut-Off Current	I _{EBO}	-	-	-10	nA	$V_{EB} = -6V$
		100	200	-	-	$I_{C} = -10 \text{mA}, V_{CE} = -1 \text{V}$
DC Current Transfer Static Ratio (Note 10)	h	100	200	300		$I_{C} = -1A, V_{CE} = -1V$
	h _{FE}	75	140	-		I _C = -5A, V _{CE} = -1V
		-	35	-		$I_{C} = -20A, V_{CE} = -2V$
		-	-50	-75	m∨	$I_{\rm C} = -500 {\rm mA}, I_{\rm B} = -20 {\rm mA}$
Collector Emitter Seturation Voltage (Note 10)	N/	-	-85	-140		I _C = -1A, I _B = -20mA
Collector-Emitter Saturation Voltage (Note 10)	V _{CE(sat)}	-	-190	-270		$I_{\rm C} = -2A, I_{\rm B} = -200 {\rm mA}$
		-	-350	-440		I _C = -5.5A, I _B = -500mA
Base-Emitter Saturation Voltage (Note 10)	V _{BE(sat)}	-	-1100	-1250	mV	I _C = -5.5A, I _B = -500mA
Base-Emitter Turn-On Voltage (Note 10)	V _{BE(on)}	-	-900	-1060	mV	I _C = -5.5A, V _{CE} = -1V
Transitional Frequency (Note 10)	f _T	-	100	-	MHz	$I_{C} = -100 \text{mA}, V_{CE} = -10 \text{V}, f = 50 \text{MHz}$
Output Capacitance	Cobo	-	122	-	pF	V _{CB} = -10V, f = 1MHz
Switching Time	ton	-	120	-		$V_{CC} = -10V, I_{C} = -4A,$
Switching Time	t _{OFF}	-	130	-	ns	$I_{B1} = -I_{B2} = -400 \text{mA}$

Note: 10. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.





Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

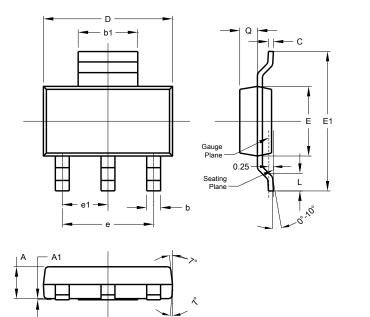






Package Outline Dimensions

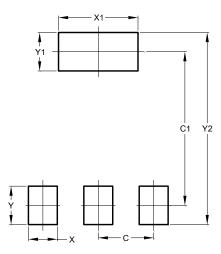
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



SOT223					
Dim	Min	Max	Тур		
Α	1.55	1.65	1.60		
A1	0.010	0.15	0.05		
b	0.60	0.80	0.70		
b1	2.90	3.10	3.00		
С	0.20	0.30	0.25		
D	6.45	6.55	6.50		
ш	3.45	3.55	3.50		
E1	6.90	7.10	7.00		
e	-	-	4.60		
e1	-	-	2.30		
L	0.85	1.05	0.95		
q	0.84	0.94	0.89		
All Dimensions in mm					

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.30
C1	6.40
Х	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00





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